# Rational Catalyst Design for Enhanced and Controlled Growth of CNT Carpets via Water-Assisted CVD



Integrity ★ Service ★ Excellence

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- Prof. Shohei Chiashi
- Maiko Terao

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# Outline



- Motivation and overview
- Role of water and growth termination
  - Ostwald ripening & subsurface diffusion phenomena
- Influence of support-metal interactions (SMI)
  - Carpet growth (catalyst activity & lifetime)
  - 3D evolution of the catalyst
- Features of a good catalyst support
  - Porosity
  - Active site density
  - Powerful tool for predicting activity of supports
- Conclusions



# Vertically Aligned SWCNTs

- "Carpets" or "forests" of SWCNTs are of interest in a number of applications
  - Membranes
  - Supercapacitors
  - Super hydrophobic surfaces
  - "Gecko" tapes
  - Li ion batteries
  - Polymer-nanotube composites
  - Field emission sources
- Collective properties and carpet / SWCNT uniformity are important







#### Inputs

- Energy (heat)
- Very small metal catalyst
- Carbon source

#### Typical Growth Processes

- Carbon arc discharge
- Laser ablation
- Chemical vapor deposition (CVD)
  - Thermal CVD
    - HiPco
    - Hydrocarbon
  - Plasma-enhanced CVD
    - Microwave
    - DC
    - Rf









- First report of SWCNT carpet growth was performed using alcohol CVD at 800°C on quartz-supported Co-Mo catalyst
  - Growth for 1h leads to 1.5  $\mu m$  long tubes
  - SWCNT growth requires high temperatures, leading to catalyst 'poisoning'

Murakami et al., Chem. Phys. Lett., 2004, 385, 298.







- Activity and lifetime of the catalysts are enhanced by water
- •Highly dense SWCNT carpets up to 2.5 mm are grown
- •Carbon purity of carpets is >99.98%
- •But growth terminates after about 20 30 min



What is the role of water during super growth?

(1) K. Hata, D.N. Futaba, K. Mizuno, T. Namai, M. Yumura, S. Iijima, *Science* 2004, *306*, 1362
(2) Futaba, Hata, Namai, Yamada, Mizuno, Hayamizu, Yumura, Iijima,., *J. Phys. Chem. B* 2006, *110*, 8035
(3) Futaba, Hata, Yamada, Mizuno, Yumura, Iijima, *Phys. Rev. Lett.* 2005, *95*, 056104



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Vacuum Pump

Pint, et al., J. Phys. Chem. C 2009, 113, 4125.

- Hot filament produces atomic hydrogen – allows rapid catalyst reduction
- Typical flow rates of precursor gases: ~ 400 sccm H<sub>2</sub>, 2 sccm C<sub>2</sub>H<sub>2</sub>, and 2 sccm H<sub>2</sub>O (at 750 °C)
- Reactor pressure = 1.4Torr
- Catalyst support: 10nm (AlxOy)
- Catalyst: Fe (0.5nm)





### Mechanisms Proposed for Growth Termination of CNTs



- Accumulation of amorphous carbon on active catalyst sites
  - lijima, et al. Science 2004, 306, 1362; Yamada et al. Nano Lett. 2008, 8, 4288.
  - Helveg et al. *Nature* **2004**, *427*, 426.
- Formation of a silicide
  - Guggenheim, R. et al. Appl. Phys. Lett. 2002, 80, 2383
- The size of the catalyst and the stability of the carbide phase
  - Harutyunyan, A.R. et al. Phys. Rev. Lett. 2008, 100, 195502
- Chemical-mechanical coupling of the top surface of the catalyst film
  - Strano, M.S. et al. ACS Nano 2008, 2, 53



10



# Lifetime of Catalyst







# Catalysts live longer with water!

Amama, Pint, McJilton, Kim, Stach, Murray, Hauge, Maruyama, Nano Lett. 2009, 9, 44.



# **Ostwald Ripening (OR)**



- Ostwald ripening is the phenomenon by which size inhomogeneity in a particle distribution is magnified over time
- Large particles increase in size at the expense of smaller particles via atomic interdiffusion
- Number density decreases, avg. diameter increases
- The driving force for Ostwald ripening is the reduction of surface energy

5-eV LEEM images of the coarsening of Au catalyst droplets on Si(111) at 600  $^\circ\text{C}$ 





Graphic from Wikipedia.org



Wilhelm Ostwald Discovered OR in 1896

The number of droplets decreases with time as larger droplets grow at the expense of smaller ones <u>The influence of the surface migration of gold on the growth of silicon nanowires</u> Hannon, Kodambaka, Ross, Tromp, *Nature*, **2006**, *440*, 69-71.





# Effect of Water on Ostwald Ripening Rate







#### Catalyst Particles Formed After Thermal Annealing





#### H<sub>2</sub> (5 min)

H<sub>2</sub>+H<sub>2</sub>O (5 min)

Water preserves particles that have sizes less than 6nm; 5-6nm  $Fe_2O_3$  particles correspond to Fe particles in the range of 3-4 nm; SWCNT mean diameter is ~3 nm



# Catalyst Nanoparticles Formed After Thermal Annealing



#### AFM topography images of $Fe_2O_3$ nanoparticles



#### H<sub>2</sub>, 5 min

Mean feature height = 3.5 nm

#### $H_2+H_2O$ , 5 min

Mean feature height = 2.6 nm

Amama, Pint, McJilton, Kim, Stach, Murray, Hauge, Maruyama, Nano Lett. 2009, 9, 44.





### Exposed Catalyst Layer After SWCNT Growth



- Following growth for 30s in C<sub>2</sub>H<sub>2</sub>
- Again, clear signs of Ostwald ripening, but is limited for the H<sub>2</sub>O case

Amama, Nano Lett. 2009, 9, 44.



Amama, Pint, McJilton, Kim, Stach, Murray, Hauge, Maruyama, Nano Lett. 2009, 9, 44.

Growth Ostwald Fe Fe Migration Termination Ripening 15 minutes 30 seconds Hydroxyl **Stabilization** он он он он 🖧 он он он он от

**Growth Termination Mechanism** 







#### Thermal Annealing : 750°C in H<sub>2</sub>/H<sub>2</sub>O



Amama, Pint, McJilton, Kim, Stach, Murray, Hauge, Maruyama, Nano Lett. 2009, 9, 44.

#### Thermal Annealing : 750°C in H<sub>2</sub>/H<sub>2</sub>O



Kim, Pint, Amama, Zakharov, Hauge, Maruyama, Stach, J. Phys. Chem. Lett. 2010, 1, 918. 19



Mass Loss via OR and SSD

- Ostwald ripening dominates in the early part of growth
- Not only is ripening observed, but we also observe Fe loss …
- Both phenomena may be intrinsically linked to the growth process
- Fe migration into a more stable, highcoordination bulk site
- Atomic Fe diffuses into the alumina and form particles in pores
- Diffusion of catalyst will cause mass loss from the catalyst that grow CNTs causing termination

Kim, Pint, Amama, Zakharov, Hauge, Maruyama, Stach, J. Phys. Chem. Lett. 2010, 1, 918.



Fe particles











- Gas environment: Extended reduction in hydrogen leads to excessive coarsening (rapid insertion, water, atomic hydrogen, low H<sub>2</sub> conc.)
- Molybdenum used in steels to impede Ostwald ripening (Resasco's CoMoCat)
- Action of ferrocene may be to resupply Fe to shrinking catalysts, keeping them large enough to continue growth





# Summary (I)



- Ostwald ripening has been demonstrated to be reduced under supergrowth conditions
- The extended lifetime of supergrowth catalysts can thus be explained by the decreased rate of Ostwald ripening / coarsening through the ability of oxygen and hydroxyl species to reduce migration of catalyst atoms
- We propose that growth stops as Ostwald ripening and subsurface diffusion deplete the catalyst
- The reduction in the number of particles observed during heat treatment correlates with the number of CNTs that stop growing
- Dynamic catalyst evolution during growth contributes to growth termination





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- Stability and activity of catalyst during SWCNT carpet growth is sensitive to the properties of the support
- Co catalyst supported on different crystal faces of Al<sub>2</sub>O<sub>3</sub>
   (A-, R- and C-faces) shows different catalyst behavior
   Ohno et al. *Jpn. J. Appl. Phys.* 2008, 47, 1956.
- Co-Mo catalyst supported on different supports produces SWCNTs with different (*n*,*m*) selectivity
  - Wang, Li, & Chen, J. Mater. Sci. 2009, 44, 3285.
- Fe catalyst (<0.6nm) supported on SiO<sub>2</sub>, Al<sub>2</sub>O<sub>3</sub> and Al<sub>2</sub>O<sub>x</sub>, shows different growth behaviors
  - Noda et al. Jpn. J. Appl. Phys. 2007, 46, L399.







Hata et al., Science 2004 Li et al., Adv. Mater. 2006 Pint et al., JPC C 2009 Mattevi et a

Mattevi et al., JPC C 2008



Mattevi et al., JPC C 2008 Yoshihara et al., JPC C 2008 Amama et al., Carbon 2012

- •The catalyst commonly used for SWNT carpet growth: Al<sub>2</sub>O<sub>3</sub> (10-200nm)/Fe (< 1 nm)
- •Other supporting layers (SiO<sub>2</sub>, TiN, MgO and ZrO<sub>2</sub>) do not appear to support aligned SWNT growth





- Participation of the second se
- •Al<sub>2</sub>O<sub>3</sub>/Fe provides increased CNT nucleation density (Mattevi *et al. J. Phys. Chem. C* **2008**, *112*, 12207)
- •Alumina is able to reduce Ostwald ripening due to the stronger catalyst-substrate interaction
- •The chemical similarity between Fe<sup>3+</sup> and Al<sup>3+</sup> partly accounts for the strong interaction (Sushumna and Ruckenstein *J. Catal.* **1985**, *90*, 4726)
- •Alumina helps to preserve the Fe (111) crystallographic planes that are known to have high catalytic activity and inhibit the less active Fe (100) and (110) planes (Sormorjai *et al. J. Phys. Chem.* **1986**, *90*, 4726)







Thickness of AlxOy film: 10 nm

- •E-beam: particles deposited have limited mobility; more lacunas
- •Sputtering: powerful electron bombardment; higher defect density
- •ALD: slow; well-controlled; atomic layers deposited sequentially
- •Sapphire; c-cut single crystal [0001]









Amama, Pint, Kim, McJilton, Eyink, Stach, Hauge, Maruyama, ACS Nano 2010, 4, 895.



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### Effect of Alumina Type on Catalyst Activity



- There is a strong dependence of the SWCNT carpet height on the type of alumina used as support
- Sputtered/Fe supports a faster growth rate and shows the longest life time followed by e-beam/Fe
- Annealed e-beam/Fe results in early growth termination
- Sapphire/Fe does not support carpet growth



Catalyst activity: sputtered/Fe > e-beam/Fe > ALD/Fe > sapphire/Fe

Amama, Pint, Kim, McJilton, Eyink, Stach, Hauge, Maruyama, ACS Nano 2010, 4, 895.

# **Raman Spectroscopy**



Catalyst	G/D (1.5 min)	G/D (5 min)	G/D (15 min)
ALD/Fe	9.89	13.32	12.02
Sputtered/Fe	22.0	28.88	29.17
E-beam/Fe	13.63	18.29	20.0
Sapphire/Fe	3.04	1.97	N/A

Amama, Pint, Kim, McJilton, Eyink, Stach, Hauge, Maruyama, ACS Nano 2010, 4, 895.







# Catalyst Evolution in the Absence of C<sub>2</sub>H<sub>2</sub>





Annealing time (min

### Catalyst Nanoparticles Formed on Different Alumina Types





Plan-view TEM images of Fe particles formed on the different alumina flavors after exposure to growth conditions in the absence of  $C_2H_2$  for 15min

Inset histograms: PSDs and N in a 100  $\times$  100 nm<sup>2</sup> area

Sputtered/Fe and ebeam/Fe have higher number density

Annealed e-beam/Fe is characterized by severe OR

Amama, et al., ACS Nano 2010, 4, 895



# XPS Sputter Depth Profile Analysis

20

15

2p<sub>3/2</sub>/AI

5

( )

2p

С Ц



— E-beam/Fe

ALD/Fe

80

Sputtering time (sec)

40

- Sputtered/Fe

Sapphire/Fe

Annealed e-beam/Fe

- Samples were sputtered for cycles of 15 sec using Ar<sup>+</sup> with KE = 1 KeV
- Each sputtering step was estimated to produce a depth of ~0.5 nm
- The catalyst evolution is analyzed on the basis of the ratio of the integrated peak areas of Fe 2p<sub>3/2</sub> and Al 2p as a function of sputtering time.
- The inward diffusion of Fe in alumina increases in the following order: sapphire/Fe < annealed/Fe < ALD/Fe < sputtered/Fe < ebeam/Fe.

Amama, Pint, Kim, McJilton, Eyink, Stach, Hauge, Maruyama, ACS Nano 2010, 4, 895



120

160



Cross-sectional TEM images of exposed catalysts after SWCNT carpet growth for 15 min



There is high inward diffusion rate of Fe in ebeam/Fe as catalyst particles can be observed below the surface

Catalysts are only observed on the surface of for the other aluminasupported catalysts

Amama, et al., ACS Nano 2010, 4, 895.



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Amama, Pint, Kim, McJilton, Eyink, Stach, Hauge, Maruyama, ACS Nano 2010, 4, 895.



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### Relationship Between Catalytic Activity, OR Rate, and Porosity



Ostwald Ripening (OR) Rate, Alumina Porosity, & Carpet Height





### Relationship Between Catalytic Activity, SSD, and Porosity







# Subsurface Diffusion of Fe





- Ex situ XPS depth profile of samples after 5 min anneal
- Evolution of the Fe 2p core line for Al<sub>2</sub>O<sub>3</sub>/Fe, MgO/Fe, ZrO<sub>2</sub>/Fe and TiN/Fe after sputter-etching for 10 cycles (depth of 5 nm)
- Fe 2p<sub>3/2</sub> can be resolved into two chemical states: Fe<sup>3+</sup> (710.6 710.8eV) and Fe<sup>0</sup> (707eV)
- Fe on the surface is strongly oxidized while as penetration depth increases Fe becomes more reduced
- Predominance of oxidized Fe in MgO/Fe suggest possible reaction
- Inward diffusion of Fe is lowest in Al<sub>2</sub>O<sub>3</sub>/Fe



Amama, Pint, Mirri, Pasquali, Hauge, Maruyama, Carbon, 2012, 50, 2396







- The catalytic activity increases in the following order: sapphire/Fe < annealed/Fe < ALD/Fe < e-beam/Fe < sputtered/Fe
- SWCNT carpet growth is maximized by very low Ostwald ripening rate, mild subsurface diffusion rate, and high porosity, which is best achieved in sputtered/Fe
- Our results will benefit current efforts aimed at rational design of catalysts with longer lifetime and enhanced activity for SWCNT carpet growth





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# Surface Roughness and Porosity of Alumina





	Alumina sample	RMS roughness (nm)	Refractive index ( <i>n</i> ) at 750nm*
า	Sapphire	0.10 ± 0.01	1.77
	ALD	0.15 ± 0.02	1.63
	E-beam	0.27± 0.02	1.57
า	Sputtered	0.14± 0.01	1.47

\*Determined using ellipsometry

- The surface topography and geometry strongly influences the contact angle measurement
- Contact angle measurement is unaffected if  $R_{rms}$  is in the subnanometer range;  $R_{rms}$  values are in the range of 0.1 0.3 nm

# **Surface Analysis Techniques**







### Surface Energy: Wetting Phenomena





The Young's equation relates the contact angle  $\theta$  of a sessile drop to the interfacial surface energies:

$$\gamma_{S} = \gamma_{L} \cos(\theta) + \gamma_{SL}$$

 $\gamma_{\rm S}$ : solid-vapor surface energy  $\gamma_{\rm L}$ : liquid-vapor surface energy  $\gamma_{\rm SL}$ : solid-liquid interfacial energy

•  $\theta$  is a measure of the competing tendencies between the energy of cohesion of the liquid molecules and the energy of adhesion between the solid and liquid

•The higher the water contact angle, the more hydrophobic the solid surface and the lower the surface free energy

•Alumina surface is usually covered with OH groups, which have strong attractive interactions with polar molecules like water.





# Static Water Contact Angles for Alumina Surfaces



	Sapp	ohire	E-beam		ALD		Sputtered	
Droplets	LCA (°)	RCA (°)	LCA (°)	RCA (°)	LCA (°)	RCA (°)	LCA (°)	RCA (°)
1	69.63	68.28	60.12	59.62	56.14	56.24	54.67	52.35
2	72.55	73.57	62.54	60.53	58.06	57.00	62.91	63.85
3	72.78	70.78	61.36	63.08	57.44	56.93	62.43	63.75
4	71.67	72.14	59.49	59.61	58.47	58.42	63.15	62.34
5	77.53	75.13	65.22	64.54	59.76	59.60	63.03	63.93
6	75.65	75.86	62.32	62.13	58.94	59.32	59.70	61.70
7	74.99	73.84	61.06	61.19	60.73	60.47	63.12	62.60
8	78.80	79.10	62.56	62.38	62.90	62.91	57.13	51.97
9	61.79	67.67	59.86	60.26	62.56	62.29	58.56	55.68
10	71.98	67.29	59.71	60.09	61.53	61.32	58.66	55.40
	72.55	± 4.24	61.38	± 1.67	59.55	± 2.22	59.84	<b>± 4.01</b>

Surface free energy: sapphire < amorphous films



Amama, Putnam, & Maruyama DISTRIBUTION A. Approved for public release; distribution unlimited.





According to the Oss-Chaudhury-Good (VOCG) model, the total surface energy  $\gamma_{TOT}$  consist of two components:

$$\gamma_{TOT} = \gamma^{LW} + \gamma^{AB}$$

 $\gamma^{LW}$ : apolar component; accounting for Lifshitz-van der Waals interactions  $\gamma^{AB}$ : polar component; accounting for acid-base or electron donor-acceptor interactions

$$\gamma^{AB} = 2\sqrt{\gamma^+ \gamma^-}$$

 $\gamma^+$ : Lewis-acid component, electron acceptor

 $\gamma$ -: Lewis-base component, electron donor

The relationship between  $\gamma^{LW}$ ,  $\gamma^+$ , and  $\gamma^+$  of a solid surface and the known  $\gamma_L$  of probe liquidscan be determined using the Young-Dupré equation:

$$\gamma_L(\cos\theta_L + 1) = 2\left(\sqrt{\gamma_S^{LW}\gamma_L^{LW}} + \sqrt{\gamma_S^+\gamma_L^-} + \sqrt{\gamma_S^-\gamma_L^+}\right)$$
I. Chem. Rev. **1988**, 88, 927 Apolar Polar

van Oss et a









### Young Dupré equation: $\gamma_L(\cos\theta_L + 1) = 2\left(\sqrt{\gamma_S^{LW}\gamma_L^{LW}} + \sqrt{\gamma_S^+\gamma_L^-} + \sqrt{\gamma_S^-\gamma_L^+}\right)$

Alumina support	Surface free energy components and total surface free energy					Carpet height	
		(mJ/m²)					
	Apolar, γ <sup>LW</sup>	Polar, γ <sup>AB</sup>	Acidic, γ⁺	Basic, Y <sup>-</sup>	γ <sub>τοτ</sub>	After 15 min	
Sapphire	26.7	9.9	2.1	11.9	36.7	0	
ALD	45.0	7.4	0.2	56.3	52.4	12.0	
E-beam	39.3	10.1	0.4	61.9	49.4	20.0	
Sputtered	38.0	7.6	0.2	65.7	45.6	29.2	47



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![](_page_48_Picture_0.jpeg)

- The apolar component is the major surface free energy component
- The Lewis basic components ( $\gamma^2$ ) are much higher than their Lewis acidic components ( $\gamma^2$ )
- Sputter-deposited alumina shows the strongest basic or electron donating character

- Magrez et al. (ACS Nano, **2011**, *5*, 3428) showed dramatic CNT carpet growth enhancement (1000x longer) when the catalyst support is treated with a basic solution

A simple, reliable, and non-destructive tool based on contact angle measurements is described for predicting the activity of catalyst supports in carbon nanotube (CNT) carpet growth

Amama, Putnam, Barron, & Maruyama (Manuscript in review)

![](_page_48_Picture_8.jpeg)

![](_page_49_Picture_0.jpeg)

O Is peak width (FWHM) vs the OH fraction as determined by constrained curve fitting of the peak

![](_page_49_Figure_2.jpeg)

Brand et al. Surf. Interface Anal. 2004, 36, 81

Alumina supports are enriched in hydroxyl groups at the surface/subsurface Hydroxyl enrichment decreases in the order: Sputtered > e-beam > ALD > sapphire

![](_page_49_Picture_5.jpeg)

![](_page_50_Picture_0.jpeg)

1.4

![](_page_50_Picture_1.jpeg)

Relationship between O/AI atomic ratios and OH fraction Sputtered 1.9 E-beam 0 evaporated and oxidized ALD 1.8 acid-pretreated aluminium 2.2 alkaline-pretreated aluminium Sapphire  $\diamond$ pseudoboehmite 1.7 anhydrous amorphous aluminium oxide 2.0 predicted relation **D/AI** ratio O/AI ratio 1.6 1.8 1.5 1.6 1.4

1.3 0.0 0.1 0.2 0.5 0.4 0.3 0 20 40 80 100 120 140 60 OH fraction Etching time (sec) Brand et al. Surf. Interface Anal. 2004, 36, 81

Alumina film thickness: 50nm thick

Alumina supports are enriched in hydroxyl groups at the surface/subsurface Hydroxyl enrichment decreases in the order: Sputtered > e-beam > ALD > sapphire

![](_page_50_Picture_6.jpeg)

# Effect of Hydroxyl Enrichment on Carpet Height

![](_page_51_Figure_1.jpeg)

![](_page_51_Picture_2.jpeg)

![](_page_52_Picture_0.jpeg)

![](_page_52_Figure_1.jpeg)

![](_page_53_Picture_0.jpeg)

![](_page_53_Picture_1.jpeg)

![](_page_53_Picture_2.jpeg)

The catalytic activity of  $AI_xO_y$ /Fe during SWCNT carpet growth is enhanced with the following attributes:

#### •Support

- High porosity of alumina
- High surface free energy for the Lewis basic component
- High hydroxyl enrichment on the surface/subsurface

#### Catalyst-support

- Low Ostwald ripening rate
- Mild subsurface diffusion rate

![](_page_53_Picture_11.jpeg)

![](_page_54_Picture_0.jpeg)

![](_page_54_Picture_2.jpeg)

- Dynamic catalyst evolution plays a significant role in growth termination
- SWCNT carpet growth is maximized by very low Ostwald ripening rate, mild subsurface diffusion rate, high porosity, and high surface free energy for the basic component ( $\gamma^{-}$ )
- A simple, reliable, and non-destructive tool for predicting the activity of catalyst supports is demonstrated

![](_page_54_Picture_6.jpeg)

![](_page_55_Picture_0.jpeg)

![](_page_55_Picture_2.jpeg)

- Air Force Office of Scientific Research (AFOSR)
- Dr. Benji Maruyama (AFRL)
- Dr. Eric Stach (Brookhaven National Lab)
- Dr. Bob Hauge (Rice Univ)
- Prof. Cary Pint (Vanderbilt Univ)
- Dr. Seung Min Kim (Samsung)
- Prof. Shawn Putnam (Univ of Central Florida)

![](_page_55_Picture_10.jpeg)

![](_page_56_Picture_0.jpeg)

![](_page_56_Picture_2.jpeg)

(1) Amama, Pint, McJilton, Kim, Stach, Murray, Hauge, Maruyama, Nano Lett. **2009**, *9*, 44.

- (2) Amama, Pint, Kim, McJilton, Eyink, Stach, Hauge, Maruyama, ACS Nano **2010**, *4*, 895.
- (3) Kim, Pint, Amama, Zakharov, Hauge, Maruyama, Stach, *J. Phys. Chem. Lett.* **2010**, *1*, 918.
- (4) Kim, Pint, Amama, Hauge, Maruyama, Stach, *J. Mater. Res.* **2010**, *25*, 1875.
- (5) Amama, Pint, Mirri, Pasquali, Hauge, Maruyama, Carbon, **2012**, *50*, 2396
- (6) Amama, Putnam, Barron, Maruyama, (Manuscript in review)

![](_page_56_Picture_9.jpeg)

![](_page_57_Picture_0.jpeg)

![](_page_57_Picture_2.jpeg)

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![](_page_57_Picture_10.jpeg)